2SC5725

Silicon NPN epitaxial planar type

For DC-DC converter

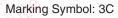
Features

- \bullet Low collector-emitter saturation voltage $V_{CE(sat)}$
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing

Unit: mm 0.40+0.10 0.16+0.10 Ц3 50+ 2 ť (0.95) (0.95) 0.65 1.9±0.1 2.90+0.20 1.1+0.2 1.1+0.3 1: Base 0 to 0.1 2: Emitter 3: Collector EIAJ: SC-59 Mini3-G1 Package

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	20	V	
Collector-emitter voltage (Base open)	V _{CEO}	15	V	
Emitter-base voltage (Collector open)	V _{EBO}	5	V	
Collector current	I _C	2	А	
Peak collector current	I _{CP}	6	Α	
Collector power dissipation *	P _C	600	mW	
Junction temperature	Tj	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	



Note) *: Measure on the ceramic substrate at $15 \text{ mm} \times 15 \text{ mm} \times 0.6 \text{ mm}$

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 10 \ \mu A, I_{\rm E} = 0$	20	ş		V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$	15			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = 10 \ \mu A, I_{\rm C} = 0$	-5			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 10 \text{ V}, I_E = 0$,		0.1	μΑ
Forward current transfer ratio *	h _{FE1}	$V_{CE} = 2 V, I_C = 100 mA$	200		800	
	h _{FE2}	$V_{CE} = 2 V, I_C = 1.5 A$	120			
Collector-emitter saturation voltage *	V _{CE(sat)}	$I_{\rm C} = 0.5 \text{ A}, I_{\rm B} = 25 \text{ mA}$		40	100	mV
		$I_{\rm C} = 1.5 \text{ A}, I_{\rm B} = 30 \text{ mA}$		130	280	
Transition frequency	f _T	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		280		MHz
Collector output capacitance	C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		15	25	pF
(Common base, input open circuited)						

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors. 2. *: Pulse measurement

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